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Details

Product Status	Discontinued at Digi-Key
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	CANbus, I ² C, IrDA, LINbus, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I ² S, POR, PWM, WDT
Number of I/O	37
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 12bit SAR; D/A 12bit
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-TQFP
Supplier Device Package	48-TQFP (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32tg11b140f64gq48-ar

- **Timers/Counters**
 - 2 × 16-bit Timer/Counter
 - 3 or 4 Compare/Capture/PWM channels (4 + 4 on one timer instance)
 - Dead-Time Insertion on one timer instance
 - 2 × 32-bit Timer/Counter
 - 32-bit Real Time Counter and Calendar (RTCC)
 - 32-bit Ultra Low Energy CRYOTIMER for periodic wakeup from any Energy Mode
 - 16-bit Low Energy Timer for waveform generation
 - 16-bit Pulse Counter with asynchronous operation
 - Watchdog Timer with dedicated RC oscillator
- **Low Energy Sensor Interface (LESENSE)**
 - Autonomous sensor monitoring in Deep Sleep Mode
 - Wide range of sensors supported, including LC sensors and capacitive buttons
 - Up to 16 inputs
- **Ultra efficient Power-on Reset and Brown-Out Detector**
- **Debug Interface**
 - 2-pin Serial Wire Debug interface
 - 4-pin JTAG interface
 - Micro Trace Buffer (MTB)
- **Pre-Programmed UART Bootloader**
- **Wide Operating Range**
 - 1.8 V to 3.8 V single power supply
 - Integrated DC-DC, down to 1.8 V output with up to 200 mA load current for system
 - Standard (-40 °C to 85 °C T_A) and Extended (-40 °C to 125 °C T_J) temperature grades available
- **Packages**
 - QFN32 (5x5 mm)
 - TQFP48 (7x7 mm)
 - QFN64 (9x9 mm)
 - TQFP64 (10x10 mm)
 - QFN80 (9x9 mm)
 - TQFP80 (12x12 mm)

3. System Overview

3.1 Introduction

The Tiny Gecko Series 1 product family is well suited for any battery operated application as well as other systems requiring high performance and low energy consumption. This section gives a short introduction to the MCU system. The detailed functional description can be found in the Tiny Gecko Series 1 Reference Manual. Any behavior that does not conform to the specifications in this data sheet or the functional descriptions in the Tiny Gecko Series 1 Reference Manual are detailed in the EFM32TG11 Errata document.

A block diagram of the Tiny Gecko Series 1 family is shown in [Figure 3.1 Detailed EFM32TG11 Block Diagram on page 10](#). The diagram shows a superset of features available on the family, which vary by OPN. For more information about specific device features, consult [Ordering Information](#).

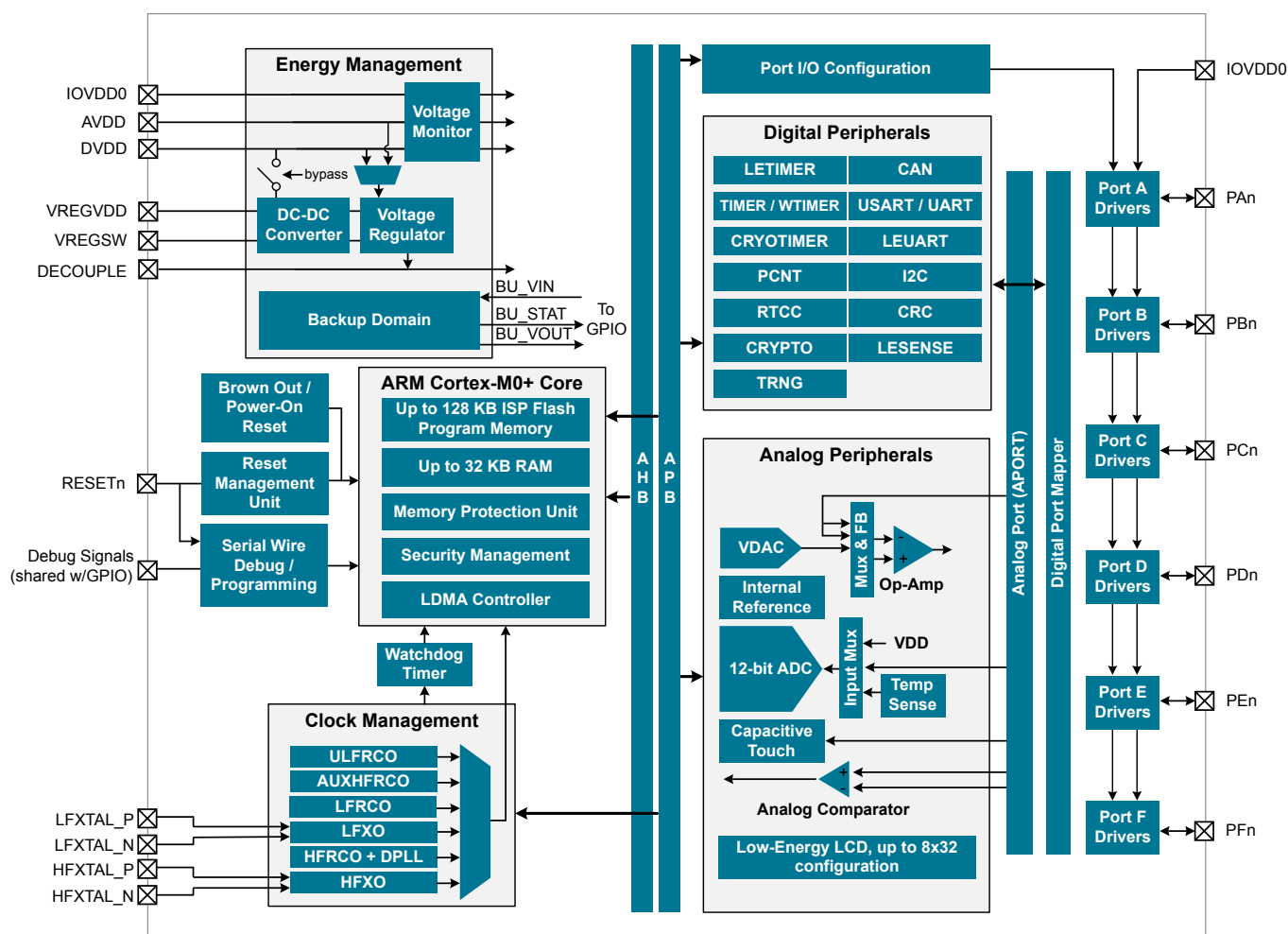


Figure 3.1. Detailed EFM32TG11 Block Diagram

4.1.2.1 General Operating Conditions

Table 4.2. General Operating Conditions

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Operating ambient temperature range ⁶	T _A	-G temperature grade	-40	25	85	°C
		-I temperature grade	-40	25	125	°C
AVDD supply voltage ²	V _{AVDD}		1.8	3.3	3.8	V
VREGVDD operating supply voltage ^{2 1}	V _{VREGVDD}	DCDC in regulation	2.4	3.3	3.8	V
		DCDC in bypass, 50mA load	1.8	3.3	3.8	V
		DCDC not in use. DVDD externally shorted to VREGVDD	1.8	3.3	3.8	V
VREGVDD current	I _{VREGVDD}	DCDC in bypass, T ≤ 85 °C	—	—	200	mA
		DCDC in bypass, T > 85 °C	—	—	100	mA
DVDD operating supply voltage	V _{DVDD}		1.62	—	V _{VREGVDD}	V
IOVDD operating supply voltage	V _{IOVDD}	All IOVDD pins ⁵	1.62	—	V _{VREGVDD}	V
DECOUPLE output capacitor ^{3 4}	C _{DECOUPLE}		0.75	1.0	2.75	μF
HFCORECLK frequency	f _{CORE}	VSCALE2, MODE = WS1	—	—	48	MHz
		VSCALE2, MODE = WS0	—	—	25	MHz
		VSCALE0, MODE = WS1	—	—	20	MHz
		VSCALE0, MODE = WS0	—	—	10	MHz
HFCLK frequency	f _{HFCLK}	VSCALE2	—	—	48	MHz
		VSCALE0	—	—	20	MHz
HFSRCCLK frequency	f _{HFSRCCLK}	VSCALE2	—	—	48	MHz
		VSCALE0	—	—	20	MHz
HFBUSCLK frequency	f _{HFBUSCLK}	VSCALE2	—	—	48	MHz
		VSCALE0	—	—	20	MHz
HFPERCLK frequency	f _{HFPERCLK}	VSCALE2	—	—	48	MHz
		VSCALE0	—	—	20	MHz
HFPERBCLK frequency	f _{HFPERBCLK}	VSCALE2	—	—	48	MHz
		VSCALE0	—	—	20	MHz
HFPERCCLK frequency	f _{HFPERCCLK}	VSCALE2	—	—	48	MHz
		VSCALE0	—	—	20	MHz

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Current consumption in EM4H mode, with voltage scaling enabled	I _{EM4H_VS}	128 byte RAM retention, RTCC running from LFXO	—	0.82	—	μA
		128 byte RAM retention, CRYO-TIMER running from ULFRCO	—	0.45	—	μA
		128 byte RAM retention, no RTCC	—	0.45	TBD	μA
Current consumption in EM4S mode	I _{EM4S}	No RAM retention, no RTCC	—	0.07	TBD	μA
Current consumption of peripheral power domain 1, with voltage scaling enabled	I _{PD1_VS}	Additional current consumption in EM2/3 when any peripherals on power domain 1 are enabled ¹	—	0.18	—	μA
Current consumption of peripheral power domain 2, with voltage scaling enabled	I _{PD2_VS}	Additional current consumption in EM2/3 when any peripherals on power domain 2 are enabled ¹	—	0.18	—	μA

Note:

1. Extra current consumed by power domain. Does not include current associated with the enabled peripherals. See [3.2.3 EM2 and EM3 Power Domains](#) for a list of the peripherals in each power domain.
2. CMU_LFRCOCTRL_ENVREF = 1, CMU_LFRCOCTRL_VREFUPDATE = 1

4.1.12 Voltage Monitor (VMON)

Table 4.19. Voltage Monitor (VMON)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Supply current (including I _{SENSE})	I _{VMON}	In EM0 or EM1, 1 supply monitored, T ≤ 85 °C	—	6.3	TBD	μA
		In EM0 or EM1, 4 supplies monitored, T ≤ 85 °C	—	12.5	TBD	μA
		In EM2, EM3 or EM4, 1 supply monitored and above threshold	—	62	—	nA
		In EM2, EM3 or EM4, 1 supply monitored and below threshold	—	62	—	nA
		In EM2, EM3 or EM4, 4 supplies monitored and all above threshold	—	99	—	nA
		In EM2, EM3 or EM4, 4 supplies monitored and all below threshold	—	99	—	nA
Loading of monitored supply	I _{SENSE}	In EM0 or EM1	—	2	—	μA
		In EM2, EM3 or EM4	—	2	—	nA
Threshold range	V _{VMON_RANGE}		1.62	—	3.4	V
Threshold step size	N _{VMON_STESP}	Coarse	—	200	—	mV
		Fine	—	20	—	mV
Response time	t _{VMON_RES}	Supply drops at 1V/μs rate	—	460	—	ns
Hysteresis	V _{VMON_HYST}		—	26	—	mV

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Signal to noise and distortion ratio (1 kHz sine wave), Noise band limited to 250 kHz	SNDR _{DAC}	500 ksps, single-ended, internal 1.25V reference	—	60.4	—	dB
		500 ksps, single-ended, internal 2.5V reference	—	61.6	—	dB
		500 ksps, single-ended, 3.3V VDD reference	—	64.0	—	dB
		500 ksps, differential, internal 1.25V reference	—	63.3	—	dB
		500 ksps, differential, internal 2.5V reference	—	64.4	—	dB
		500 ksps, differential, 3.3V VDD reference	—	65.8	—	dB
Signal to noise and distortion ratio (1 kHz sine wave), Noise band limited to 22 kHz	SNDR _{DAC_BAND}	500 ksps, single-ended, internal 1.25V reference	—	65.3	—	dB
		500 ksps, single-ended, internal 2.5V reference	—	66.7	—	dB
		500 ksps, differential, 3.3V VDD reference	—	68.5	—	dB
		500 ksps, differential, internal 1.25V reference	—	67.8	—	dB
		500 ksps, differential, internal 2.5V reference	—	69.0	—	dB
		500 ksps, single-ended, 3.3V VDD reference	—	70.0	—	dB
Total harmonic distortion	THD		—	70.2	—	dB
Differential non-linearity ³	DNL _{DAC}		TBD	—	TBD	LSB
Integral non-linearity	INL _{DAC}		TBD	—	TBD	LSB
Offset error ⁵	V _{OFFSET}	T = 25 °C	TBD	—	TBD	mV
		Across operating temperature range	TBD	—	TBD	mV
Gain error ⁵	V _{GAIN}	T = 25 °C, Low-noise internal reference (REFSEL = 1V25LN or 2V5LN)	TBD	—	TBD	%
		Across operating temperature range, Low-noise internal reference (REFSEL = 1V25LN or 2V5LN)	TBD	—	TBD	%
External load capacitance, OUTSCALE=0	C _{LOAD}		—	—	75	pF

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Supply current, continuous conversions, WARMUP-MODE=KEEPCSENWARM	I _{CSEN_ACTIVE}	SAR or Delta Modulation conversions of 33 pF capacitor, CS0CG=0 (Gain = 10x), always on	—	90.5	—	μA
HFPERCLK supply current	I _{CSEN_HFPERCLK}	Current contribution from HFPERCLK when clock to CSEN block is enabled.	—	2.25	—	μA/MHz

Note:

- Current is specified with a total external capacitance of 33 pF per channel. Average current is dependent on how long the module is actively sampling channels within the scan period, and scales with the number of samples acquired. Supply current for a specific application can be estimated by multiplying the current per sample by the total number of samples per period (total_current = single_sample_current * (number_of_channels * accumulation)).

4.1.21.3 I2C Fast-mode Plus (Fm+)¹

Table 4.30. I2C Fast-mode Plus (Fm+)¹

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
SCL clock frequency²	f _{SCL}		0	—	1000	kHz
SCL clock low time	t _{LOW}		0.5	—	—	µs
SCL clock high time	t _{HIGH}		0.26	—	—	µs
SDA set-up time	t _{SU_DAT}		50	—	—	ns
SDA hold time	t _{HD_DAT}		100	—	—	ns
Repeated START condition set-up time	t _{SU_STA}		0.26	—	—	µs
(Repeated) START condition hold time	t _{HD_STA}		0.26	—	—	µs
STOP condition set-up time	t _{SU_STO}		0.26	—	—	µs
Bus free time between a STOP and START condition	t _{BUF}		0.5	—	—	µs

Note:

1. For CLHR set to 0 or 1 in the I2Cn_CTRL register.
2. For the minimum HPERCLK frequency required in Fast-mode Plus, refer to the I2C chapter in the reference manual.

4.2.2 DC-DC Converter

Default test conditions: CCM mode, LDCDC = 4.7 μ H, CDCDC = 4.7 μ F, VDCDC_I = 3.3 V, VDCDC_O = 1.8 V, FDCDC_LN = 7 MHz

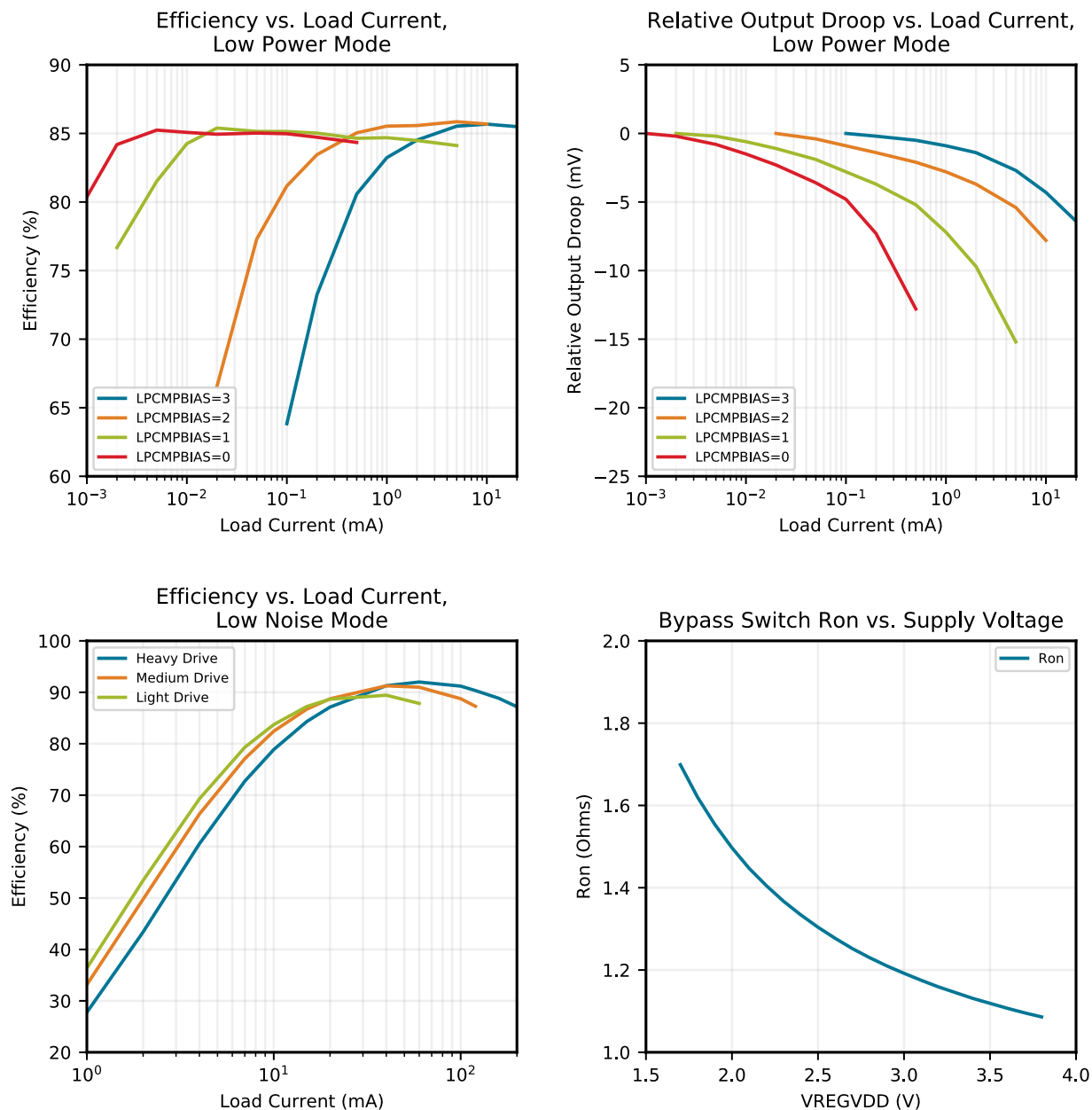


Figure 4.8. DC-DC Converter Typical Performance Characteristics

5.3 EFM32TG11B5xx in QFP64 Device Pinout

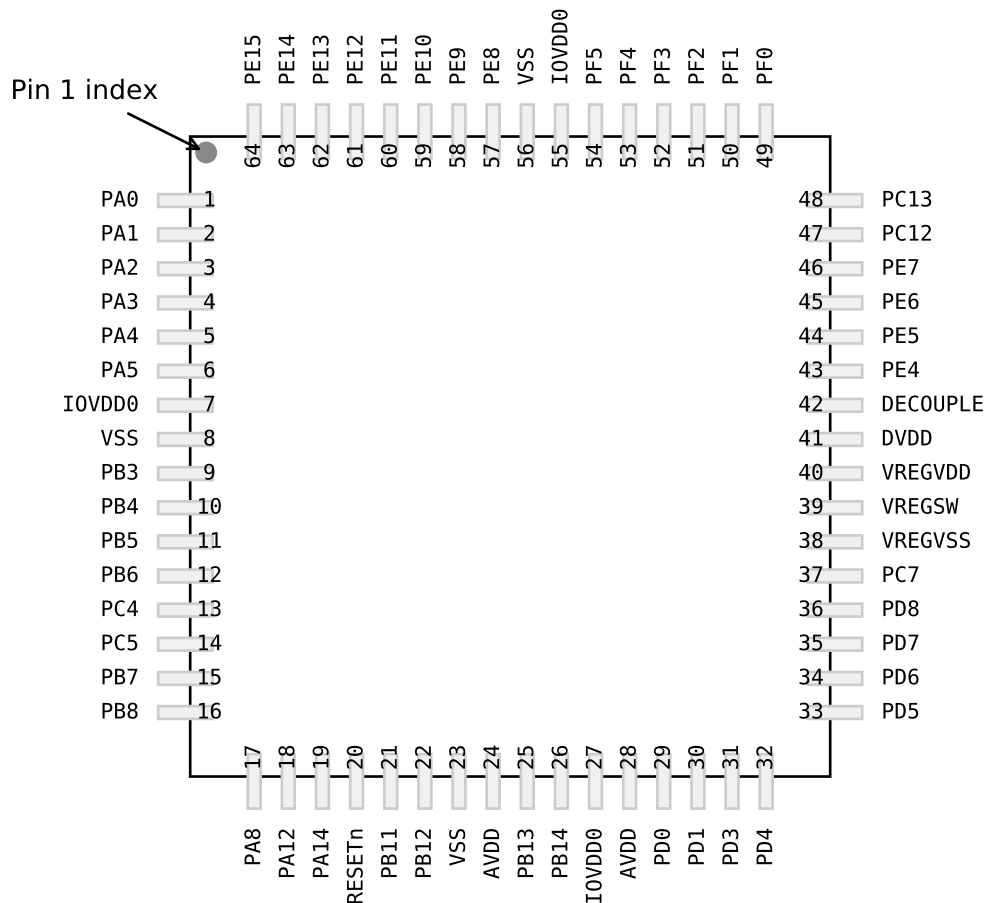


Figure 5.3. EFM32TG11B5xx in QFP64 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see [5.14 GPIO Functionality Table](#) or [5.15 Alternate Functionality Overview](#).

Table 5.3. EFM32TG11B5xx in QFP64 Device Pinout

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA0	1	GPIO	PA1	2	GPIO
PA2	3	GPIO	PA3	4	GPIO
PA4	5	GPIO	PA5	6	GPIO
IOVDD0	7 27 55	Digital IO power supply 0.	VSS	8 23 56	Ground
PB3	9	GPIO	PB4	10	GPIO
PB5	11	GPIO	PB6	12	GPIO

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PB4	10	GPIO	PB5	11	GPIO
PB6	12	GPIO	PC4	13	GPIO
PC5	14	GPIO	PB7	15	GPIO
PB8	16	GPIO	PA8	17	GPIO
PA12	18	GPIO	PA13	19	GPIO (5V)
PA14	20	GPIO	RESETn	21	Reset input, active low. To apply an external reset source to this pin, it is required to only drive this pin low during reset, and let the internal pull-up ensure that reset is released.
PB11	22	GPIO	PB12	23	GPIO
AVDD	24 28	Analog power supply.	PB13	25	GPIO
PB14	26	GPIO	PD0	29	GPIO (5V)
PD1	30	GPIO	PD3	31	GPIO
PD4	32	GPIO	PD5	33	GPIO
PD6	34	GPIO	PD7	35	GPIO
PD8	36	GPIO	PC7	37	GPIO
VREGSW	39	DCDC regulator switching node	VREGVDD	40	Voltage regulator VDD input
DVDD	41	Digital power supply.	DECOUPLE	42	Decouple output for on-chip voltage regulator. An external decoupling capacitor is required at this pin.
PE4	43	GPIO	PE5	44	GPIO
PE6	45	GPIO	PE7	46	GPIO
PC12	47	GPIO (5V)	PC13	48	GPIO (5V)
PF0	49	GPIO (5V)	PF1	50	GPIO (5V)
PF2	51	GPIO	PF3	52	GPIO
PF4	53	GPIO	PF5	54	GPIO
PE8	56	GPIO	PE9	57	GPIO
PE10	58	GPIO	PE11	59	GPIO
PE12	60	GPIO	PE13	61	GPIO
PE14	62	GPIO	PE15	63	GPIO
PA15	64	GPIO			

Note:

1. GPIO with 5V tolerance are indicated by (5V).

5.12 EFM32TG11B5xx in QFN32 Device Pinout

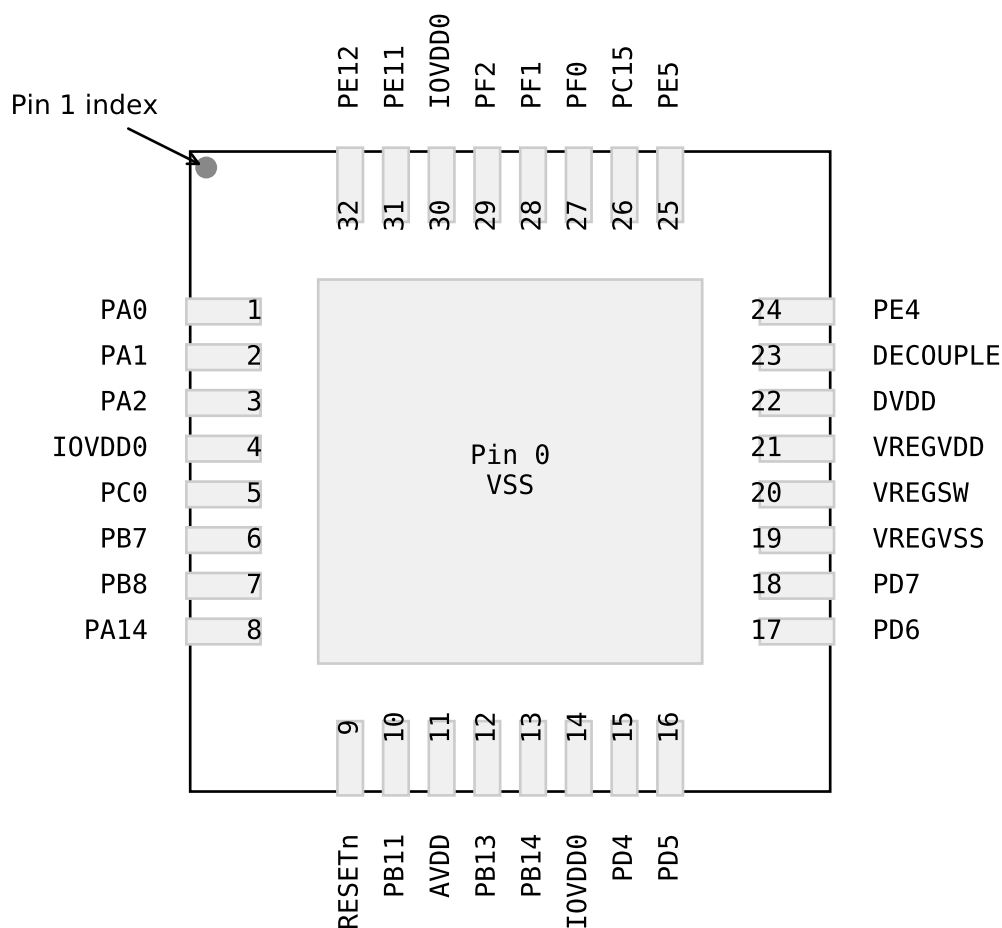


Figure 5.12. EFM32TG11B5xx in QFN32 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see [5.14 GPIO Functionality Table](#) or [5.15 Alternate Functionality Overview](#).

Table 5.12. EFM32TG11B5xx in QFN32 Device Pinout

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
VREGVSS	0 19	Voltage regulator VSS	PA0	1	GPIO
PA1	2	GPIO	PA2	3	GPIO
IOVDD0	4 14 30	Digital IO power supply 0.	PC0	5	GPIO (5V)
PB7	6	GPIO	PB8	7	GPIO

5.14 GPIO Functionality Table

A wide selection of alternate functionality is available for multiplexing to various pins. The following table shows the name of each GPIO pin, followed by the functionality available on that pin. Refer to [5.15 Alternate Functionality Overview](#) for a list of GPIO locations available for each function.

Table 5.14. GPIO Functionality Table

GPIO Name	Pin Alternate Functionality / Description			
	Analog	Timers	Communication	Other
PA0	BUSBY BUSAX LCD_SEG13	TIM0_CC0 #0 TIM0_CC1 #7 PCNT0_S0IN #4	US1_RX #5 US3_TX #0 LEU0_RX #4 I2C0_SDA #0	CMU_CLK2 #0 PRS_CH0 #0 PRS_CH3 #3 GPIO_EM4WU0
PA1	BUSAY BUSBX LCD_SEG14	TIM0_CC0 #7 TIM0_CC1 #0 PCNT0_S1IN #4	US3_RX #0 I2C0_SCL #0	CMU_CLK1 #0 PRS_CH1 #0
PA2	BUSBY BUSAX LCD_SEG15	TIM0_CC2 #0	US1_RX #6 US3_CLK #0	CMU_CLK0 #0
PA3	BUSAY BUSBX LCD_SEG16	TIM0_CDTI0 #0	US3_CS #0 U0_TX #2	CMU_CLK2 #1 CMU_CLK2 #4 CMU_CLKI0 #1 LES_AL- TEX2
PA4	BUSBY BUSAX LCD_SEG17	TIM0_CDTI1 #0	US3_CTS #0 U0_RX #2	LES_ALTEX3
PA5	BUSAY BUSBX LCD_SEG18	TIM0_CDTI2 #0	US3_RTS #0 U0_CTS #2	LES_ALTEX4 ACMP1_O #7
PA6	BUSBY BUSAX LCD_SEG19	WTIM0_CC0 #1	U0_RTS #2	PRS_CH6 #0 ACMP0_O #4 GPIO_EM4WU1
PB3	BUSAY BUSBX LCD_SEG20 / LCD_COM4	TIM1_CC3 #2 WTIM0_CC0 #6	US2_TX #1 US3_TX #2	ACMP0_O #7
PB4	BUSBY BUSAX LCD_SEG21 / LCD_COM5	WTIM0_CC1 #6	US2_RX #1	
PB5	BUSAY BUSBX LCD_SEG22 / LCD_COM6	WTIM0_CC2 #6 PCNT0_S0IN #6	US0_RTS #4 US2_CLK #1	
PB6	BUSBY BUSAX LCD_SEG23 / LCD_COM7	TIM0_CC0 #3 PCNT0_S1IN #6	US0_CTS #4 US2_CS #1	
PC0	VDAC0_OUT0ALT / OPA0_OUTALT #0 BU- SACMP0Y BUSACMP0X	TIM0_CC1 #3 PCNT0_S0IN #2	CAN0_RX #0 US0_TX #5 US1_TX #0 US1_CS #4 US2_RTS #0 US3_CS #3 I2C0_SDA #4	LES_CH0 PRS_CH2 #0
PC1	VDAC0_OUT0ALT / OPA0_OUTALT #1 BU- SACMP0Y BUSACMP0X	TIM0_CC2 #3 WTIM0_CC0 #7 PCNT0_S1IN #2	CAN0_TX #0 US0_RX #5 US1_TX #4 US1_RX #0 US2_CTS #0 US3_RTS #1 I2C0_SCL #4	LES_CH1 PRS_CH3 #0
PC2	VDAC0_OUT0ALT / OPA0_OUTALT #2 BU- SACMP0Y BUSACMP0X	TIM0_CDTI0 #3 WTIM0_CC1 #7	US1_RX #4 US2_TX #0	LES_CH2
PC3	VDAC0_OUT0ALT / OPA0_OUTALT #3 BU- SACMP0Y BUSACMP0X	TIM0_CDTI1 #3 WTIM0_CC2 #7	US1_CLK #4 US2_RX #0	LES_CH3

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
OPA3_N	0: PC7		Operational Amplifier 3 external negative input.
OPA3_OUT	0: PD1		Operational Amplifier 3 output.
OPA3_P	0: PC6		Operational Amplifier 3 external positive input.
PCNT0_S0IN	0: PC13 2: PC0 3: PD6	4: PA0 6: PB5 7: PB12	Pulse Counter PCNT0 input number 0.
PCNT0_S1IN	0: PC14 2: PC1 3: PD7	4: PA1 6: PB6 7: PB11	Pulse Counter PCNT0 input number 1.
PRS_CH0	0: PA0 1: PF3 2: PC14 3: PF2		Peripheral Reflex System PRS, channel 0.
PRS_CH1	0: PA1 1: PF4 2: PC15 3: PE12		Peripheral Reflex System PRS, channel 1.
PRS_CH2	0: PC0 1: PF5 2: PE10 3: PE13		Peripheral Reflex System PRS, channel 2.
PRS_CH3	0: PC1 1: PE8 2: PE11 3: PA0		Peripheral Reflex System PRS, channel 3.
PRS_CH4	0: PC8 2: PF1		Peripheral Reflex System PRS, channel 4.
PRS_CH5	0: PC9 2: PD6		Peripheral Reflex System PRS, channel 5.
PRS_CH6	0: PA6 1: PB14 2: PE6		Peripheral Reflex System PRS, channel 6.
PRS_CH7	0: PB13 2: PE7		Peripheral Reflex System PRS, channel 7.

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
VDAC0_OUT0 / OPA0_OUT	0: PB11		Digital to Analog Converter DAC0 output channel number 0.
VDAC0_OUT0ALT / OPA0_OUTALT	0: PC0 1: PC1 2: PC2 3: PC3	4: PD0	Digital to Analog Converter DAC0 alternative output for channel 0.
VDAC0_OUT1 / OPA1_OUT	0: PB12		Digital to Analog Converter DAC0 output channel number 1.
VDAC0_OUT1ALT / OPA1_OUTALT	0: PC12 1: PC13 2: PC14 3: PC15	4: PD1	Digital to Analog Converter DAC0 alternative output for channel 1.
WTIM0_CC0	0: PE4 1: PA6	4: PC15 6: PB3 7: PC1	Wide timer 0 Capture Compare input / output channel 0.
WTIM0_CC1	0: PE5	4: PF0 6: PB4 7: PC2	Wide timer 0 Capture Compare input / output channel 1.
WTIM0_CC2	0: PE6	4: PF1 6: PB5 7: PC3	Wide timer 0 Capture Compare input / output channel 2.
WTIM0_CDTI0	0: PE10 2: PA12	4: PD4	Wide timer 0 Complimentary Dead Time Insertion channel 0.
WTIM0_CDTI1	0: PE11 2: PA13	4: PD5	Wide timer 0 Complimentary Dead Time Insertion channel 1.
WTIM0_CDTI2	0: PE12 2: PA14	4: PD6	Wide timer 0 Complimentary Dead Time Insertion channel 2.
WTIM1_CC0	0: PB13 1: PD2 2: PD6 3: PC7	5: PE7	Wide timer 1 Capture Compare input / output channel 0.
WTIM1_CC1	0: PB14 1: PD3 2: PD7	4: PE4	Wide timer 1 Capture Compare input / output channel 1.
WTIM1_CC2	0: PD0 1: PD4 2: PD8	4: PE5	Wide timer 1 Capture Compare input / output channel 2.

Table 5.18. ADC0 Bus and Pin Mapping

APORT4Y	APORT4X	APORT3Y	APORT3X	APORT2Y	APORT2X	APORT1Y	APORT1X	APORT0Y	APORT0X	Port
BUSDY	BUSDY	BUSCY	BUSCX	BUSBY	BUSBX	BUSAY	BUSAX	BUSADC0Y	BUSADC0X	Bus
										CH31
				PB14			PB14			CH30
					PB13	PB13				CH29
				PB12			PB12			CH28
					PB11	PB11				CH27
										CH26
										CH25
										CH24
										CH23
				PB6			PB6			CH22
	PF5	PF5			PB5	PB5				CH21
PF4			PF4	PB4			PB4			CH20
PF2	PF3	PF3			PB3	PB3				CH19
			PF2							CH18
	PF1	PF1								CH17
PF0			PF0							CH16
	PE15	PE15			PA15	PA15				CH15
PE14			PE14	PA14			PA14			CH14
	PE13	PE13			PA13	PA13				CH13
PE12			PE12							CH12
	PE11	PE11								CH11
PE10			PE10	PA10			PA10			CH10
	PE9	PE9			PA9	PA9				CH9
PE8			PE8							CH8
	PE7	PE7						PD7	PD7	CH7
PE6			PE6	PA6			PA6	PD6	PD6	CH6
	PE5	PE5			PA5	PA5		PD5	PD5	CH5
PE4			PE4	PA4			PA4	PD4	PD4	CH4
					PA3	PA3		PD3	PD3	CH3
				PA2			PA2	PD2	PD2	CH2
					PA1	PA1		PD1	PD1	CH1
				PA0			PA0	PD0	PD0	CH0

6. TQFP80 Package Specifications

6.1 TQFP80 Package Dimensions

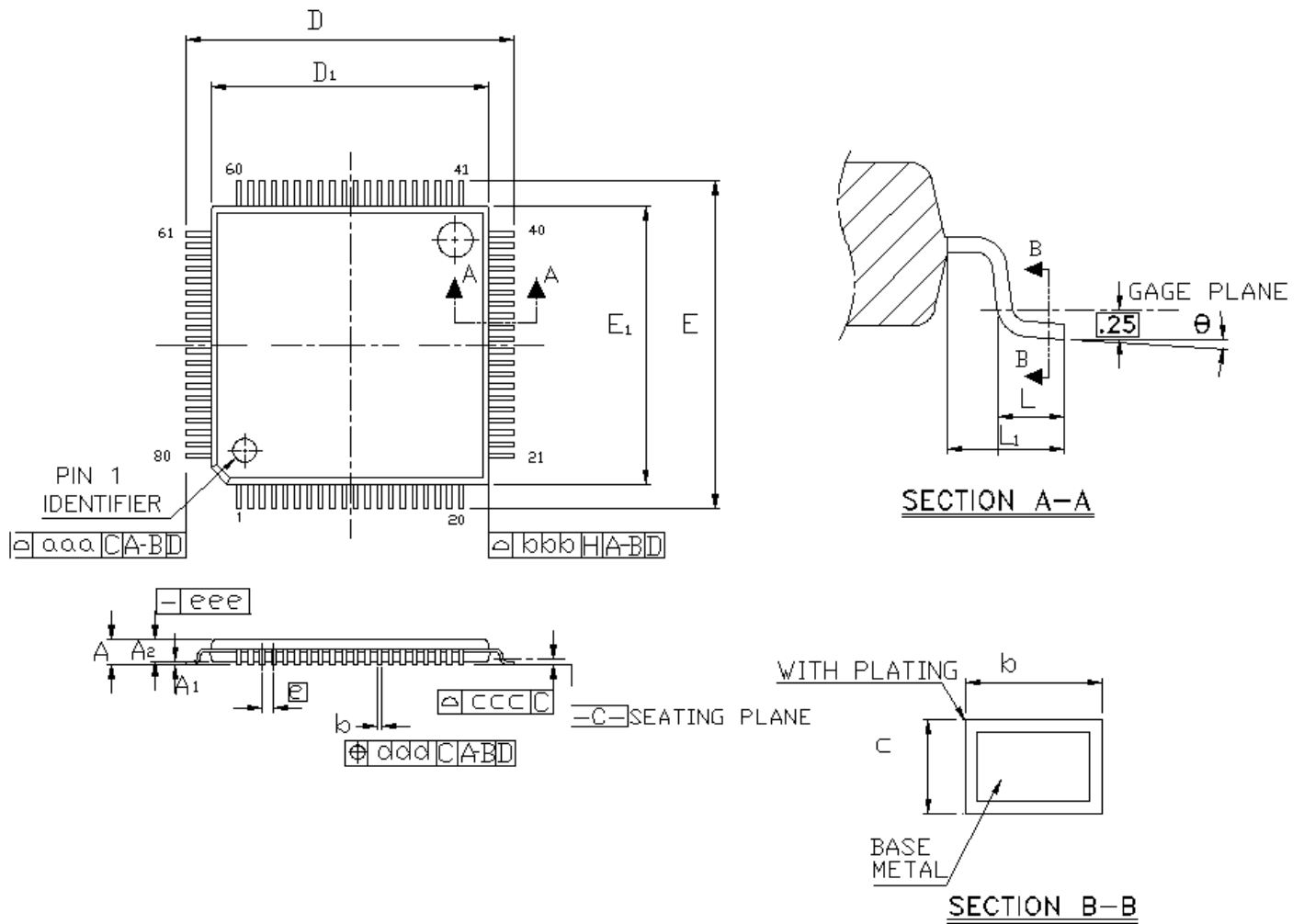


Figure 6.1. TQFP80 Package Drawing

7.3 QFN80 Package Marking



Figure 7.3. QFN80 Package Marking

The package marking consists of:

- P P P P P P P P P P – The part number designation.
- T T T T T T – A trace or manufacturing code. The first letter is the device revision.
- Y Y – The last 2 digits of the assembly year.
- W W – The 2-digit workweek when the device was assembled.

Table 9.2. QFN64 PCB Land Pattern Dimensions

Dimension	Typ
C1	8.90
C2	8.90
E	0.50
X1	0.30
Y1	0.85
X2	7.30
Y2	7.30

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. This Land Pattern Design is based on the IPC-7351 guidelines.
3. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05mm.
4. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.
5. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
6. The stencil thickness should be 0.125 mm (5 mils).
7. The ratio of stencil aperture to land pad size can be 1:1 for all pads.
8. A 3x3 array of 1.45 mm square openings on a 2.00 mm pitch can be used for the center ground pad.
9. A No-Clean, Type-3 solder paste is recommended.
10. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

12. Revision History

Revision 0.5

February, 2018

- [4.1 Electrical Characteristics](#) updated with latest characterization data and production test limits.
- Added [4.1.3 Thermal Characteristics](#).
- Added [4.2 Typical Performance Curves](#) section.
- Corrected OPA / VDAC output connections in [Figure 5.14 APORT Connection Diagram on page 119](#).

Revision 0.1

May 1st, 2017

Initial release.